

# 54LS174/DM54LS174/DM74LS174, 54LS175/DM54LS175/DM74LS175 Hex/Quad D Flip-Flops with Clear

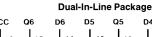
#### **General Description**

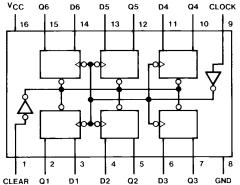
These positive-edge-triggered flip-flops utilize TTL circuitry to implement D-type flip-flop logic. All have a direct clear input, and the guad (175) versions feature complementary outputs from each flip-flop.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output.

- LS174 contains six flip-flops with single-rail outputs
- LS175 contains four flip-flops with double-rail outputs
- Buffered clock and direct clear inputs
- Individual data input to each flip-flop
- Applications include:
  - Buffer/storage registers Shift registers
  - Pattern generators
- Typical clock frequency 40 MHz Typical power dissipation per flip-flop 14 mW
- Alternate Military/Aerospace device 54LS175) is available. Contact a National Semiconductor Sales Office/Distributor for specifications.

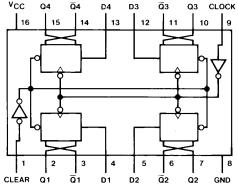
#### **Connection Diagrams**





Order Number 54LS174DMQB, 54LS174FMQB, 54LS174LMQB, DM54LS174J, DM54LS174W, DM74LS174M or DM74LS174N See NS Package Number E20A, J16A, M16A, N16E or W16A

#### **Dual-In-Line Package**



TL/F/6404-2

Order Number 54LS175DMQB, 54LS175FMQB, 54LS175LMQB, DM54LS175J DM54LS175W, DM74LS175M or DM74LS175N See NS Package Number E20A, J16A, M16A, N16E or W16A

#### Function Table (Each Flip-Flop)

	Inputs	Outputs			
Clear	Clear Clock D			<b>Q</b> †	
L	Х	Х	L	Н	
Н	1 ↑	Н	Н	L	
Н	<b>↑</b>	L	L	Н	
Н	L	Х	Q <sub>0</sub>	$\overline{Q}_0$	

H = High Level (steady state)

L = Low Level (steady state)

X = Don't Care

= The level of Q before the indicated steady-state input conditions were

= LS175 only

#### **Absolute Maximum Ratings (Note)**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 7V
Operating Free Air Temperature Range

Storage Temperature Range  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ 

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

### **Recommended Operating Conditions**

Symbol	Parameter			DM54LS174			DM74LS174			
Symbol			Min	Nom	Max	Min	Nom	Max	Units	
V <sub>CC</sub>	Supply Voltage		4.5	5	5.5	4.75	5	5.25	V	
V <sub>IH</sub>	High Level Input Vol	tage	2			2			V	
V <sub>IL</sub>	Low Level Input Volt	age			0.7			0.8	V	
loh	High Level Output Current				-0.4			-0.4	mA	
l <sub>OL</sub>	Low Level Output Current				4			8	mA	
f <sub>CLK</sub>	Clock Frequency (Note 1)		0		30	0		30	MHz	
f <sub>CLK</sub>	Clock Frequency (Note 2)		0		25	0		25	MHz	
t <sub>W</sub>	Pulse Width	Clock	20			20			ns	
	(Note 6)	Clear	20			20			113	
t <sub>SU</sub>	Data Setup Time (Note 6)		20			20			ns	
t <sub>H</sub>	Data Hold Time (Note 6)		0			0			ns	
t <sub>REL</sub>	Clear Release Time (Note 6)		25			25			ns	
T <sub>A</sub>	Free Air Operating T	emperature	-55		125	0		70	°C	

#### 'LS174 Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 3)	Max	Units	
VI	Input Clamp Voltage	$V_{CC} = Min, I_{I} = -18 \text{ mA}$				-1.5	V
V <sub>OH</sub>	High Level Output	$V_{CC} = Min, I_{OH} = Max$	DM54	2.5	3.4		V
	Voltage	$V_{IL} = Max, V_{IH} = Min$	DM74	2.7	3.4		<b></b>
V <sub>OL</sub>	Low Level Output	$V_{CC} = Min, I_{OL} = Max$	DM54		0.25	0.4	
	Voltage	$V_{IL} = Max, V_{IH} = Min$	DM74		0.35	0.5	V
		$I_{OL} = 4 \text{ mA}, V_{CC} = Min$	DM74		0.25	0.4	
I <sub>I</sub>	Input Current@Max Input Voltage	$V_{CC} = Max, V_I = 7V$				0.1	mA
I <sub>IH</sub>	High Level Input Current	$V_{CC} = Max, V_I = 2.7V$				20	μΑ
I <sub>IL</sub>	Low Level Input	V <sub>CC</sub> = Max	Clock			-0.4	
	Current	$V_I = 0.4V$	Clear			-0.4	mA
			Data			-0.36	
los	Short Circuit	V <sub>CC</sub> = Max	DM54	-20		-100	mA
	Output Current	(Note 4)	DM74	-20		-100	
Icc	Supply Current	V <sub>CC</sub> = Max (Note 5)			16	26	mA

Note 1:  $C_L=15$  pF,  $R_L=2$  k $\Omega$ ,  $T_A=25^{\circ}C$  and  $V_{CC}=5V$ .

Note 2:  $C_L = 50$  pF,  $R_L = 2$  k $\Omega$ ,  $T_A = 25$ °C and  $V_{CC} = 5V$ .

Note 3: All typicals are at  $V_{CC}=5V$ ,  $T_A=25^{\circ}C$ .

Note 4: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Note 5: With all outputs open and 4.5V applied to all data and clear inputs, I<sub>CC</sub> is measured after a momentary ground, then 4.5V applied to the clock.

Note 6:  $T_A = 25^{\circ}C$  and  $V_{CC} = 5V$ .

### **'LS174 Switching Characteristics**

at  $V_{CC} = 5V$  and  $T_A = 25^{\circ}C$  (See Section 1 for Test Waveforms and Output Load)

		From (Input) To (Output)					
Symbol	Parameter		C <sub>L</sub> = 15 pF		$C_L = 50  pF$		Units
			Min	Max	Min	Max	
f <sub>MAX</sub>	Maximum Clock Frequency		30		25		MHz
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	Clock to Output		30		32	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	Clock to Output		30		36	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	Clear to Output		35		42	ns

# **Recommended Operating Conditions**

Symbol	Parameter -			DM54LS17	5		Units		
Symbol			Min	Nom	Max	Min	Nom	Max	Office
V <sub>CC</sub>	Supply Voltage		4.5	5	5.5	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Volt	age	2			2			V
$V_{IL}$	Low Level Input Volta	age			0.7			0.8	V
I <sub>OH</sub>	High Level Output Current				-0.4			-0.4	mA
l <sub>OL</sub>	Low Level Output Current				4			8	mA
f <sub>CLK</sub>	Clock Frequency (Note 1)		0		30	0		30	MHz
f <sub>CLK</sub>	Clock Frequency (Note 2)		0		25	0		25	MHz
t <sub>W</sub>	Pulse Width	Clock	20			20			ns
	(Note 3)	Clear	20			20			113
t <sub>SU</sub>	Data Setup Time (Note 3)		20			20			ns
t <sub>H</sub>	Data Hold Time (Note 3)		0			0			ns
t <sub>REL</sub>	Clear Release Time (Note 3)		25			25			ns
T <sub>A</sub>	Free Air Operating To	emperature	-55		125	0		70	°C

Note 1:  $C_L = 15$  pF,  $R_L = 2$  k $\Omega$ ,  $T_A = 25$ °C and  $V_{CC} = 5V$ . Note 2:  $C_L = 50$  pF,  $R_L = 2$  k $\Omega$ ,  $T_A = 25$ °C and  $V_{CC} = 5V$ .

Note 3:  $T_A = 25^{\circ}C$  and  $V_{CC} = 5V$ .

#### **'LS175 Electrical Characteristics**

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$				-1.5	V
V <sub>OH</sub>	High Level Output	$V_{CC} = Min, I_{OH} = Max$	DM54	2.5	3.4		>
	Voltage	$V_{IL} = Max, V_{IH} = Min$	DM74	2.7	3.4		v
V <sub>OL</sub>	Low Level Output	out $V_{CC} = Min, I_{OL} = Max$			0.25	0.4	
	Voltage	$V_{IL} = Max, V_{IH} = Min$	DM74		0.35	0.5	V
		I <sub>OL</sub> = 4 mA, V <sub>CC</sub> = Min	DM74		0.25	0.4	
l <sub>l</sub>	Input Current@Max Input Voltage	$V_{CC} = Max, V_I = 7V$				0.1	mA
I <sub>IH</sub>	High Level Input Current	$V_{CC} = Max, V_I = 2.7V$				20	μΑ
I <sub>IL</sub>	Low Level Input	V <sub>CC</sub> = Max	Clock			-0.4	
	Current	$V_{l} = 0.4V$	Clear			-0.4	mA
			Data			-0.36	
los	Short Circuit	V <sub>CC</sub> = Max	DM54	-20		-100	mA
Output Cu	Output Current	(Note 2)	DM74	-20		-100	IIIA
Icc	Supply Current	V <sub>CC</sub> = Max (Note 3)			11	18	mA

## 'LS175 Switching Characteristics

at  $V_{CC} = 5V$  and  $T_A = 25^{\circ}C$  (See Section 1 for Test Waveforms and Output Load)

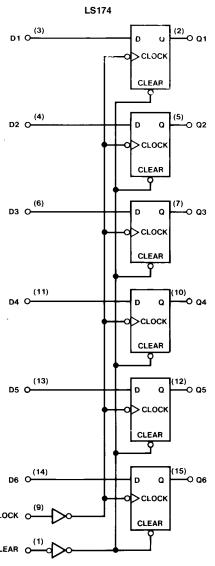
		From (Input)					
Symbol	Parameter	To (Output)	C <sub>L</sub> = 15 pF		C <sub>L</sub> = 50 pF		Units
			Min	Max	Min	Max	
f <sub>MAX</sub>	Maximum Clock Frequency		30		25		MHz
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	Clock to Q or Q		30		32	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	Clock to Q or Q		30		36	ns
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	Clear to $\overline{\mathbb{Q}}$		25		29	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	Clear to Q		35		42	ns

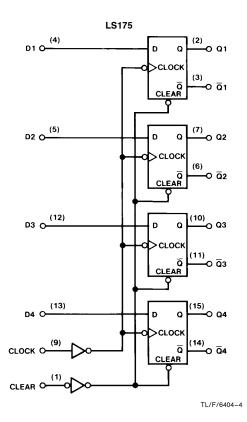
Note 1: All typicals are at  $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ .

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

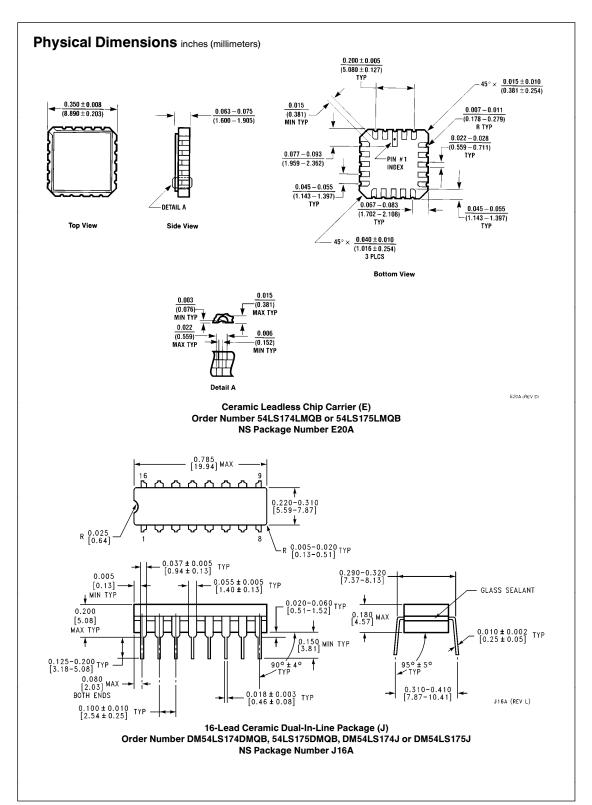
Note 3: With all outputs open and 4.5V applied to all data and clear inputs, I<sub>CC</sub> is measured after a momentary ground, then 4.5V applied to the clock input.

# Logic Diagrams

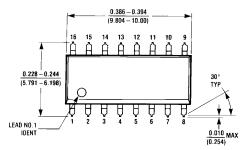


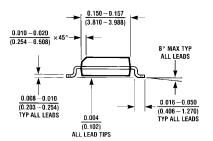


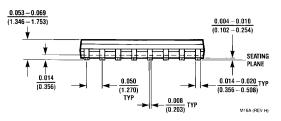
TL/F/6404-3



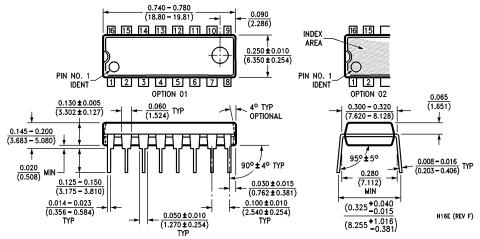
#### Physical Dimensions inches (millimeters) (Continued)



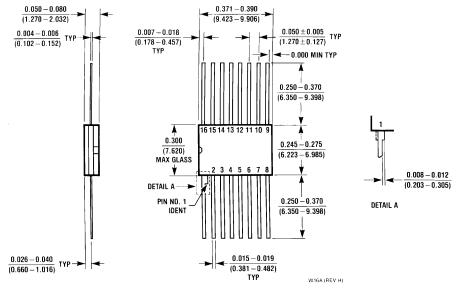




16-Lead Small Outline Molded Package (M) Order Number DM74LS174M or DM74LS175M NS Package Number M16A



16-Lead Molded Dual-In-Line Package (N) Order Number DM74LS174N or DM74LS175N NS Package Number N16E



16-Lead Ceramic Flat Package (W) Order Number 54LS174FMQB, 54LS175FMQB, DM54LS174W or DM54LS175W NS Package Number W16A

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